



DC-DC Converter Applications

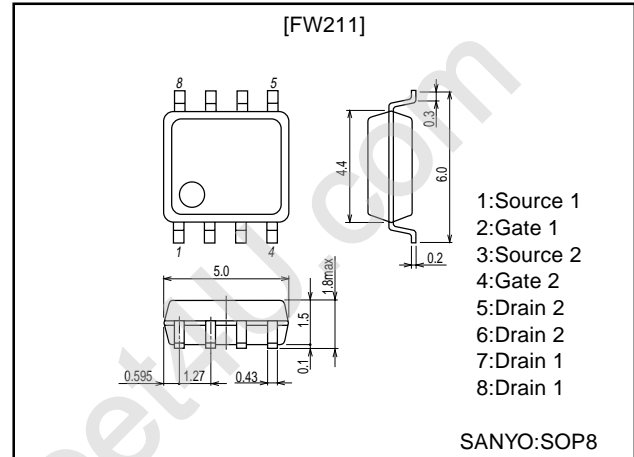
Features

- Low ON resistance.
- 2.5V drive.

Package Dimensions

unit:mm

2129



Specifications

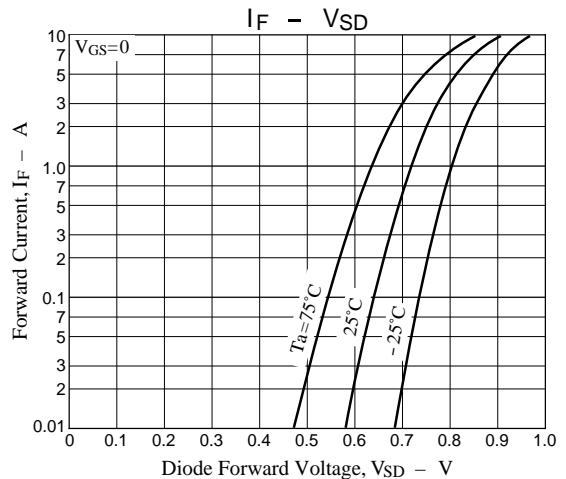
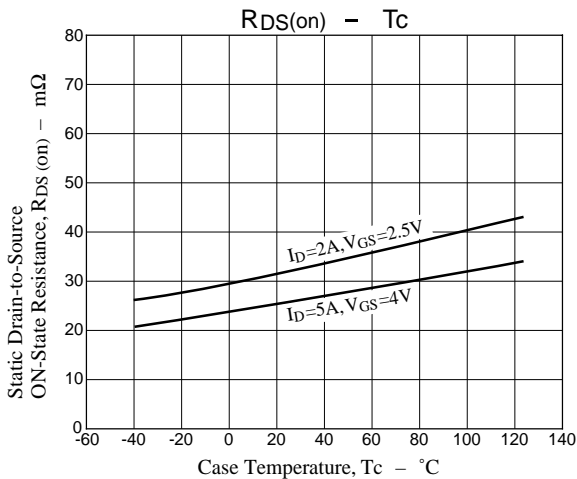
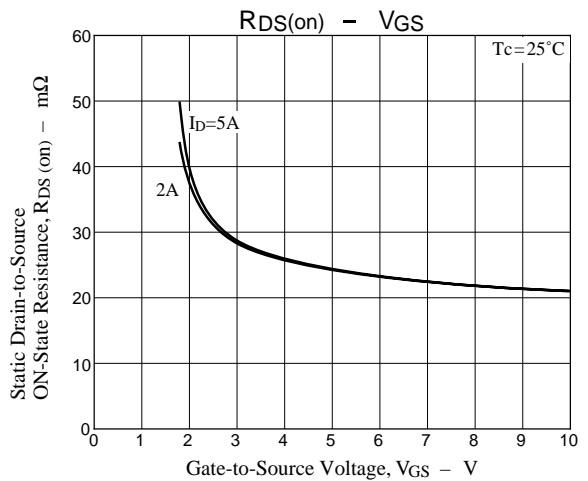
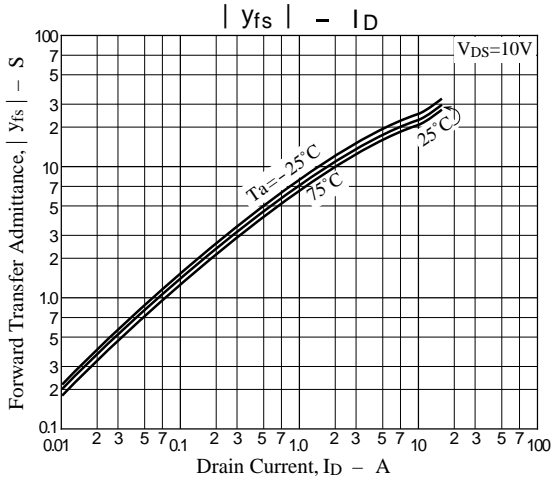
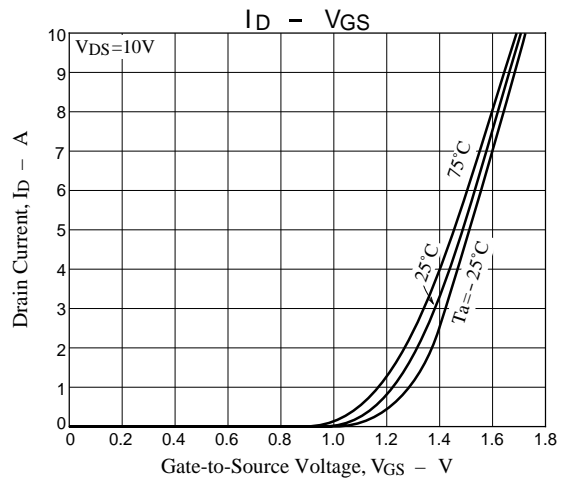
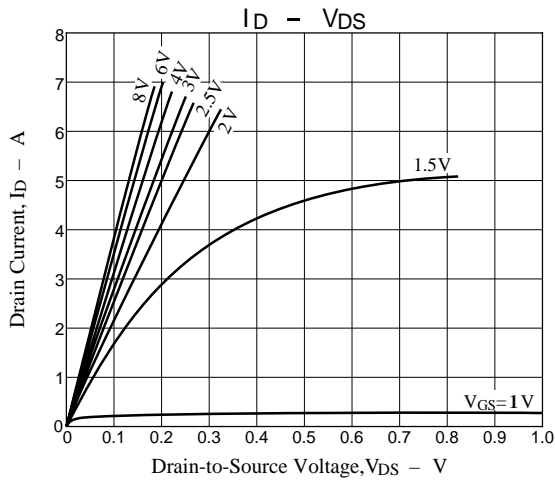
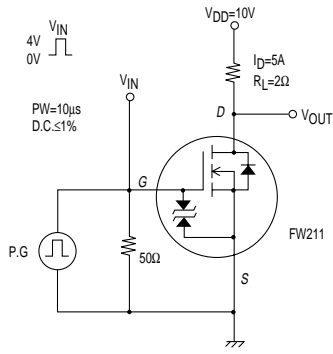
Absolute Maximum Ratings at Ta = 25°C

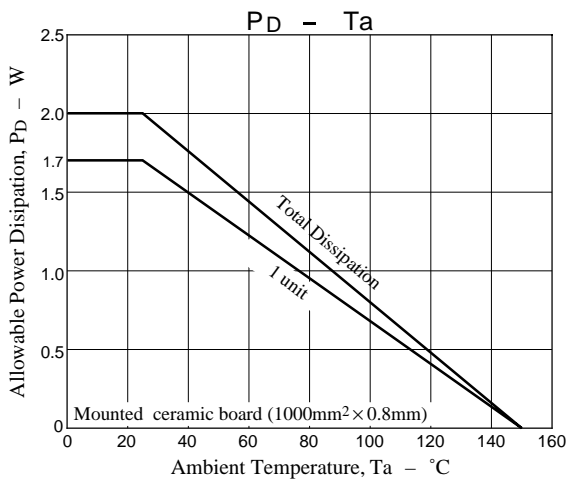
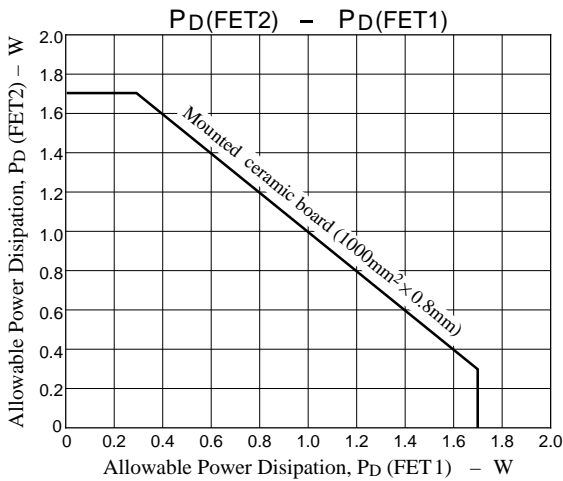
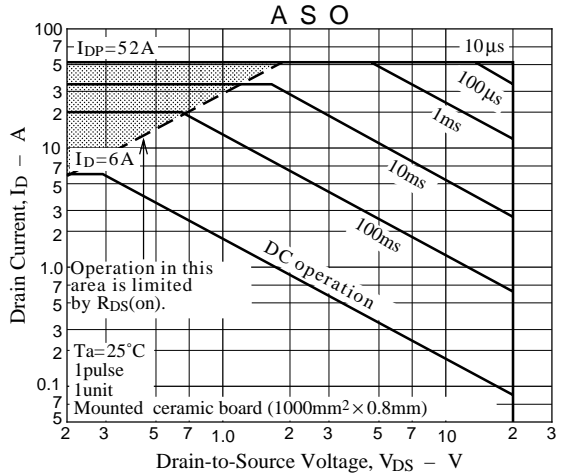
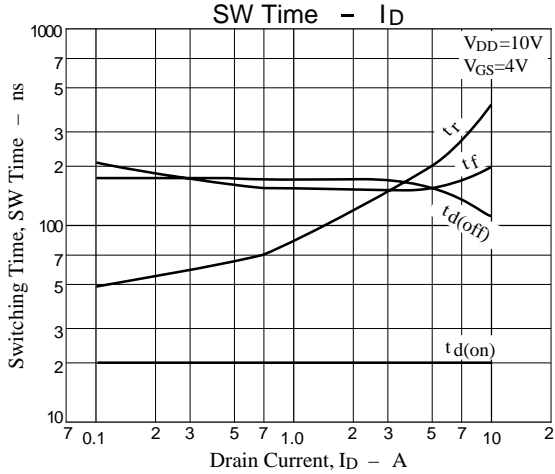
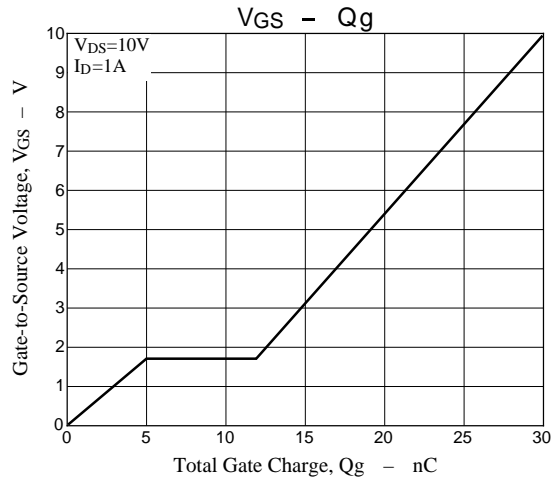
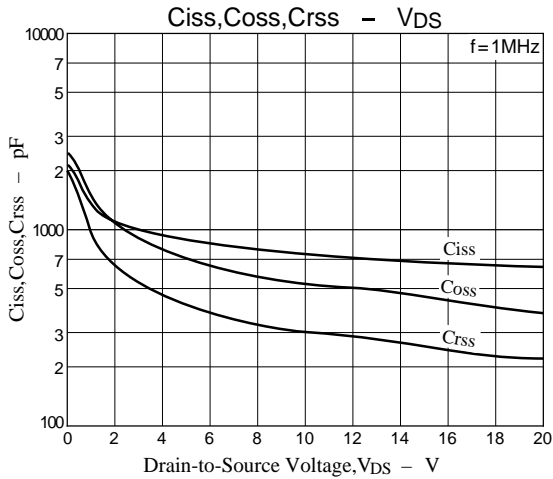
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		20	V
Gate-to-Source Voltage	V_{GSS}		±10	V
Drain Current (DC)	I_D		6	A
Drain Current (pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	52	A
Allowable Power Dissipation	P_D	Mounted on a ceramic board (1000mm ² ×0.8mm) 1unit	1.7	W
Total Dissipation	P_T	Mounted on a ceramic board (1000mm ² ×0.8mm)	2.0	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
			min	typ	max		
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA$, $V_{GS}=0$	20			V	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V$, $V_{GS}=0$			100	μA	
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V$, $V_{DS}=0$			±10	μA	
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V$, $I_D=1mA$	0.4		1.3	V	
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V$, $I_D=5A$		9	15	S	
Static Drain-to-Source ON-State Resistance	$R_{DS(on)1}$	$I_D=5A$, $V_{GS}=4V$			27	35	mΩ
	$R_{DS(on)2}$	$I_D=2A$, $V_{GS}=2.5V$			35	48	mΩ
Input Capacitance	C_{iss}	$V_{DS}=10V$, $f=1MHz$			750	pF	
Output Capacitance	C_{oss}	$V_{DS}=10V$, $f=1MHz$			520	pF	
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=10V$, $f=1MHz$			300	pF	
Turn-ON Delay Time	$t_{d(on)}$	See Specified Test Circuit			20	ns	
Rise Time	t_r	See Specified Test Circuit			200	ns	
Turn-OFF Delay Time	$t_{d(off)}$	See Specified Test Circuit			150	ns	
Fall Time	t_f	See Specified Test Circuit			150	ns	
Total Gate Charge	Q_g	$V_{DS}=10V$, $V_{GS}=10V$, $I_D=1A$			30	nC	
Gate-to-Source Charge	Q_{gs}				5	nC	
Gate-to-Drain "Miller" Charge	Q_{gd}				7	nC	
Diode Forward Voltage	V_{SD}		$I_S=5A$, $V_{GS}=0$	1.0		1.2	V

Switching Time Test Circuit





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